Quantum Rods for Displays and LEDs: Full Visible Spectral Range, Less Cd and Higher Stability

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Displays Will Be Everywhere

Street displays





Medical augmented reality

In-door and wall displays



Problems and Trends

- Hi-resolution: 4k, 8K and 10K
- Bigger size: 55", 65", 85", 100"
- The power consumption!
- The price!
- Image quality



Interactive windows





Flexible displays

Big data visualization

QD Display Configurations



Quantum Dots

Quantum Rods



0D The shape matters 1D

VS

Properties	Quantum Dots	Quantum Rods	Remarks
Thermal quenching	+	+++	Solved for QRs in this work
Whole visible range tuneable emission	+++	+++	Solved for QRs in this work
Light extraction efficiency	-	++	41% vs 20% for QDs, twice less energy losses
Linearly polarized emission	-	++	Linearly polarized PL (max. DOP is around 0.87)
Narrow symmetric emission	+++	+++	FWHM can be less for QRs
Resistance to photobleaching	++	++	
Absorption cross-section	++	+++	Less material is required
PLQY in film	++	++	

Synthesis of Truly Green and Blue Emitting Quantum Rods

Previous works are mostly limited to red and green-yellow QRs ($\lambda_{em} \ge 550$ nm) because of very large red shift of emission during shell growth.

For Displays we need green with $\lambda_{em} \approx 520$ nm



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Characterization





Zn-modified Quantum Rods Are More Stable



Direct on-chip application (QRLED)

Outstanding color gamut and luminous efficiency



Comparison with reported wide color gamut WLED

Green emitting	Red emitting	Color gamut (%	Luminous efficacy	I ₁₅₀ ^{a)}	ССТ	Refs.		
material	material	NTSC)	(lm W-1)	(%)	(K)			
Phosphors								
RbLi(Li ₃ SiO ₄) ₂ :Eu ²⁺	$K_2SiF_6:Mn^{4+}$	107	97.28	103	6221	1		
CsPbBr ₃ QDs	$Na_2WO_2F_4:Mn^{4+}$	107.1	_	2	12 123	2		
Ba _{0.75} Al ₁₁ O _{17.25} :Mn ²⁺	K ₂ SiF ₆ :Mn ⁴⁺	107.3	_	32	6645	3		
MgAl ₂ O ₄ :Mn ²⁺	$K_2SiF_6:Mn^{4+}$	116	56	105	10 342	4		
b-Sialon:Eu ²⁺	K ₂ SiF ₆ :Mn ⁴⁺	96	136	86	11770	5		
g-AlON:Mn ²⁺	K ₂ SiF ₆ :Mn ⁴⁺	102	38	_	10611	6		
RbNa(Li ₃ SiO ₄) ₂ :Eu ²⁺	K ₂ SiF ₆ :Mn ⁴⁺	113	111	102	5196	7		
$Cs_{3}Mn_{0.96}Zn_{0.04}Br_{5}$	$K_2SiF_6:Mn^{4+}$	101	107.76	87	7732	8		
$Sr_2MgAl_{22}O_{36}:Mn^{2+}$	K_2 SiF ₆ :Mn ⁴⁺	127	70.58	86	_	9		
						10		
Quantum Dots						-		
CsPbBr ₃ QDs	$K_2SiF_6:Mn^{4+}$	124	62	_	_	11		
CsPbBr ₃ QDs@glass	Cs ₂ SiF ₆ :Mn ⁴⁺	125	_	5	_	12		
CsPbBr ₃ QDs@SDDA	K ₂ SiF ₆ :Mn ⁴⁺	102	-	<60 ^{b)}	-	13		
CsPbBr ₃ QDs	$CsPb(I_{0.6}Br_{0.4})_3$ QDs	113	30	<40 ^{b)}	-	14		
CsPbBr ₃ (QDs)@ α-ZrP	$K_2SiF_6:Mn^{4+}$	125	-	<20 ^{b)}	-	15		
CsPbBr ₃ (QDs)/SiO ₂	-	126.8	58.9	<40 ^{b)}	5829	16		
CdSe//	CdSe/CdS/ZnS/CdSZnS	100	41	—	10000	17		
ZnS/CdSZnS QDs	QDs							
CdSe/ZnS QDs	CdSe/ZnS QDs	122	_	_	2763	18		
CdSe/CdZnS QDs	CdSe/CdZnS QDs	116	_	_	5410	19		
Quantum Rods								
CdSe@CdZnS QRs	CdSe@CdZnS QRs	122	115	106	8909	This Work		

a) Intensity at 150 °C relatively to r.t. emission

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